IN74AC652

Octal 3-State Bus Transceivers and D Flip-Flops

High-Speed Silicon-Gate CMOS

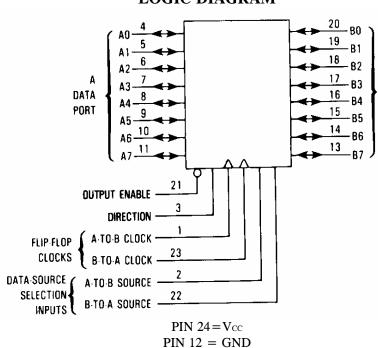
The IN74AC652 is identical in pinout to the LS/ALS652, HC/HCT652. The device inputs are compatible with standard CMOS outputs; with pullup resistors, they are compatible with LS/ALS outputs.

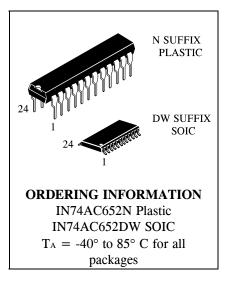
These devices consists of bus transceiver circuits, D-type flip-flop, and control circuitry arranged for multiplex transmission of data directly from the data bus or from the internal storage registers. Direction and Output Enable are provided to select the read-time or stored data function. Data on the A or B Data bus, or both, can be stored in the internal D flip-flops by low-to-high transitions at the appropriate clock pins (A-to-B Clock or B-to-A Clock) regardless of the select or enable or enable control pins. When A-to-B Source and B-to-A Source are in the real-time transfer mode, it is also possible to store data without using the internal D-type flip-flops by simultaneously enabling Direction and Output Enable. In this configuration each output reinforces its input. Thus, when all other data sources to the two sets of bus lines are at high impedance, each set of bus lines will remain at its last state.

The IN74AC652 has noninverted outputs.

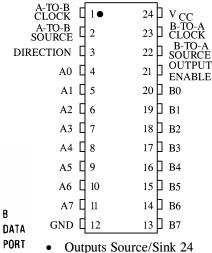
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 2.0 to 6.0 V
- Low Input Current: $1.0 \mu A$, $0.1 \mu A$ @ $25^{\circ}C$
- High Noise Immunity Characteristic of CMOS Devices

LOGIC DIAGRAM





PIN ASSIGNMENT



 Outputs Source/Sink 24 mA

MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
V_{CC}	DC Supply Voltage (Referenced to GND)	-0.5 to +7.0	V
V_{IN}	DC Input Voltage (Referenced to GND)	-0.5 to Vcc +0.5	V
Vout	DC Output Voltage (Referenced to GND)	-0.5 to Vcc +0.5	V
I _{IN}	DC Input Current, per Pin	±20	mA
Iout	DC Output Sink/Source Current, per Pin	±50	mA
Icc	DC Supply Current, Vcc and GND Pins	±50	mA
P _D	Power Dissipation in Still Air, Plastic DIP+ SOIC Package+	750 500	mW
Tstg	Storage Temperature	-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP or SOIC Package)	260	°C

^{*}Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the Recommended Operating Conditions.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit	
Vcc	DC Supply Voltage (Referenced to GND)	2.0	6.0	V	
VIN, VOUT	DC Input Voltage, Output Voltage (Referenced	0	V_{CC}	V	
Tı	Junction Temperature (PDIP)		140	°C	
TA	Operating Temperature, All Package Types	-40	+85	°C	
Іон	Output Current - High		-24	mA	
Iol	Output Current - Low		24	mA	
tr, tf	(except Schmitt Inputs)	=3.0 V =4.5 V =5.5 V	0 0	150 40 25	ns/V

 $[\]overline{^*}$ V_{IN} from 30% to 70% V_{CC}

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, $V_{\rm IN}$ and $V_{\rm OUT}$ should be constrained to the range $GND \le (V_{\rm IN} \ or \ V_{\rm OUT}) \le V_{\rm CC}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or $V_{\rm CC}$). Unused outputs must be left open.



⁺Derating - Plastic DIP: - 10 mW/°C from 65° to 125°C SOIC Package: : - 7 mW/°C from 65° to 125°C

DC ELECTRICAL CHARACTERISTICS(Voltages Referenced to GND)

			Vcc	Guarante	Guaranteed Limits		
Symbol	Parameter	Test Conditions	V	25 °C	-40°C to 85°C	Unit	
V _{IH}	Minimum High- Level Input Voltage	Vout=0.1 V or Vcc-0.1 V	3.0 4.5 5.5	2.1 3.15 3.85	2.1 3.15 3.85	V	
VIL	Maximum Low - Level Input Voltage	Vout=0.1 V or Vcc-0.1 V	3.0 4.5 5.5	0.9 1.35 1.65	0.9 1.35 1.65	V	
Vон	Minimum High- Level Output Voltage	Iout ≤ -50 μA	3.0 4.5 5.5	2.9 4.4 5.4	2.9 4.4 5.4	V	
		* V _{IN} =V _{IH} or V _{IL} I _{OH} =-12 mA I _{OH} =-24 mA I _{OH} =-24 mA	3.0 4.5 5.5	2.56 3.86 4.86	2.46 3.76 4.76		
Vol	Maximum Low- Level Output Voltage	Iουτ ≤ 50 μA	3.0 4.5 5.5	0.1 0.1 0.1	0.1 0.1 0.1	V	
		*V _{IN} =V _{IH} or V _{IL} I _{OL} =12 mA I _{OL} =24 mA I _{OL} =24 mA	3.0 4.5 5.5	0.36 0.36 0.36	0.44 0.44 0.44		
I _{IN}	Maximum Input Leakage Current	V _{IN} =V _{CC} or GND	5.5	±0.1	±1.0	μΑ	
Ioz	Maximum Three- State Leakage Current	$V_{IN}(OE) = V_{IH} \text{ or } V_{IL}$ $V_{IN} = V_{CC} \text{ or } GND$ $V_{OUT} = V_{CC} \text{ or } GND$	5.5	±0.6	±6.0	μА	
Iold	+Minimum Dynamic Output Current	Vold=1.65 V Max	5.5		75	mA	
Іонд	+Minimum Dynamic Output Current	Vohd=3.85 V Min	5.5		-75	mA	
Icc	Maximum Quiescent Supply Current (per Package)	V _{IN} =V _{CC} or GND	5.5	8.0	80	μΑ	

^{*} All outputs loaded; thresholds on input associated with output under test.

Note: I_{IN} and I_{CC} @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V_{CC}



⁺Maximum test duration 2.0 ms, one output loaded at a time.

$\label{eq:action} \textbf{AC ELECTRICAL CHARACTERISTICS} (C_L = 50 pF, Input \ t_r = t_f = 3.0 \ ns)$

		V_{CC}^*	(Guarante	d Limits		
Symbol	Parameter	V				C to °C	Unit
			Min	Max	Min	Max	
t plh	Propagation Delay, A-to-B Clock or B-to-A Clock to A or B Data Port (Figure 1)	3.3 5.0	4.0 2.5	17.0 12.0	3.0 2.0	19.0 14.0	ns
t PHL	Propagation Delay, A-to-B Clock or B-to-A Clock to A or B Data Port (Figure 1)	3.3 5.0	3.0 2.0	14.5 10.5	2.5 1.5	16.5 12.0	ns
t PLH	Propagation Delay, Input A to Output B or Input B to Output A (Figures 2,3)	3.3 5.0	3.0 2.0	14.0 9.5	2.5 1.5	16.0 11.0	ns
t PHL	Propagation Delay, Input A to Output B or Input B to Output A (Figures 2,3)	3.3 5.0	2.5 1.5	13.0 9.0	2.0 1.0	15.0 10.5	ns
t PLH	Propagation Delay, A-to-B Source or B-to-A Source to A or B Data Port (Figure 4)	3.3 5.0	3.0 2.5	14.0 10.0	2.5 2.0	16.0 11.5	ns
t PHL	Propagation Delay, A-to-B Source or B-to-A Source to A or B Data Port (Figure 4)	3.3 5.0	2.5 2.0	13.5 10.0	2.0 1.5	15.5 11.5	ns
tрzн	Propagation Delay, Output Enable to A Data Port (Figure 5)	3.3 5.0	2.5 1.5	12.0 9.0	2.0 1.0	13.5 10.0	ns
t pzl	Propagation Delay, Output Enable to A Data Port (Figure 5)	3.3 5.0	2.5 1.5	12.0 9.0	2.0 1.0	14.0 10.5	ns
t PHZ	Propagation Delay, Output Enable to A Data Port (Figure 5)	3.3 5.0	3.0 2.0	13.0 11.0	2.5 1.5	14.0 12.0	ns
t PLZ	Propagation Delay, Output Enable to A Data Port (Figure 5)	3.3 5.0	2.5 2.0	12.5 10.5	2.0 1.5	14.0 12.0	ns
tрzн	Propagation Delay, Direction to B Data Port (Figure 6)	3.3 5.0	3.0 2.0	12.5 9.5	2.5 1.5	14.0 10.5	ns
t pzl	Propagation Delay, Direction to B Data Port (Figure 6)	3.3 5.0	2.5 1.5	12.5 9.5	2.0 1.0	14.5 11.0	ns
t PHZ	Propagation Delay, Direction to B Data Port (Figure 6)	3.3 5.0	3.5 2.5	13.5 11.5	3.0 2.0	14.5 12.5	ns
t plz	Propagation Delay, Direction to B Data Port (Figure 6)	3.3 5.0	3.0 2.5	13.5 11.5	2.5 2.0	15.0 13.0	ns
Cin	Maximum Input Capacitance	5.0	4.5 4.5				pF
Соит	Input/Output Capacitance	5.0	1	.5	1:	5	pF

		Typical @25°C,V _{CC} =5.0 V	
C_{PD}	Power Dissipation Capacitance	60	pF

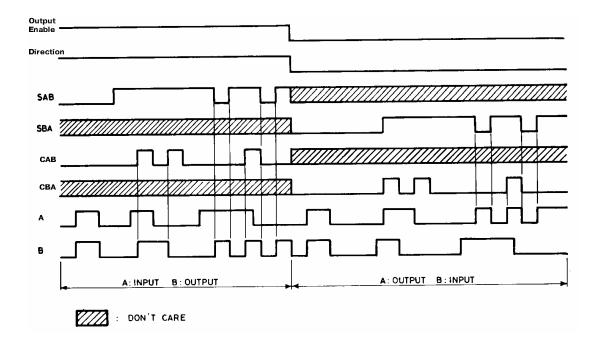
*Voltage Range 3.3 V is 3.3 V ± 0.3 V Voltage Range 5.0 V is 5.0 V ± 0.5 V



TIMING REQUIREMENTS(C_L=50pF, Input t_r=t_f=3.0 ns)

			Guarantee		
Symbol	Parameter	V	25 °C	-40°C to 85°C	Unit
t su	Minimum Setup Time, A or B Data Port to A-to-B Clock or B-to-A Clock (Figure 7)	5.0	7.0	8.0	ns
th	Minimum Hold Time, A-to-B Clock or B-to-A Clock to A or B Data Port (Figure 7)	5.0	2.5	2.5	ns
t _w	Minimum Pulse Width, A-to-B Clock or B-to-A Clock (Figure 7)	5.0	6.0	7.0	ns

TIMING DIAGRAM





FUNCTION TABLE

Dir.	OE	CAB	CBA	SAB	SBA	A	В	FUNCTION
						INPUTS	INPUTS	Both the A bus and the B bus are inputs.
L	Н	X	X	X	X	Z	Z	The output functions of the A and B bus are disabled.
		4	4	X	X	INPUTS	INPUTS	Both the A and B bus are used for inputs to the internal flip-flops. Data at the bus will be stored on low to high transition of the clock inputs.
						OUTPUTS	INPUTS	The A bus are outputs and the B bus are inputs.
		\mathbf{X}^*	X	X	L	L H	L H	The data at the B bus are displayed at the A bus.
L	L	X^*	4	X	L	L H	L H	The data at the B bus are displayed at the A bus. The data of the B bus are stored to the internal flip-flops on low to high transition of the clock pulse.
		X^*	X	X	Н	Qn	X	The data stored to the internal flip-flops, are displayed at the A bus.
		X*	Ļ ∤	X	Н	H L	H L	The data at the B bus are stored to the internal flip-flops on low to high transition of the clock pulse. The states of the internal flip-flops output directly to the A bus.
						INPUTS	OUTPUTS	The A bus are inputs and the B bus are outputs.
		X	\mathbf{X}^*	L	X	L H	L H	The data at the A bus are displayed at the B bus.
Н	Н	 4	\mathbf{X}^*	L	X	L H	L H	The data at the B bus are displayed at the A bus. The data of the B bus are stored to the internal flip-flops on low to high transition of the clock pulse.
		X	\mathbf{X}^*	Н	X	X	Qn	The data stored to the internal flip-flops are displayed at the B bus.
		4	\mathbf{X}^*	Н	X	L H	L H	The data at the A bus are stored to the internal flip-flops on low to high transition of the clock pulse. The states of the internal flip-flops output directly to the B bus.
						OUTPUTS	OUTPUTS	Both the A bus and the B bus are outputs
Н	L	X	X	Н	Н	Qn	Qn	The data stored to the internal flip-flops are displayed at the A and B bus respectively.
	12T C A	<u></u> F	-	Н	Н	Qn	Qn	The output at the A bus are displayed at the B bus, the output at the B bus are displayed at the A bus respec.

X: DON'T CARE

Z: HIGH IMPEDANCE

 $\mbox{Qn}: \mbox{THE DATA STORED TO THE INTERNAL FLIP-FLOPS BY MOST RECENT LOW TO HIGH TRANSITION OF THE CLOCK INPUTS$

 st : THE DATA AT THE A AND B BUS WILL BE STORED TO THE INTERNAL FLIP-FLOPS ON EVERY LOW TO TRANSITION OF THE CLOCK INPUTS



SWITCHING DIAGRAMS

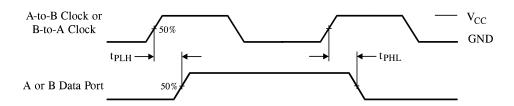
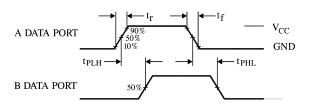


Figure 1. Switching Waveforms



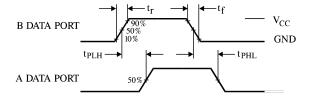
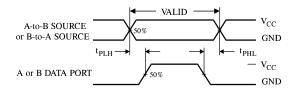


Figure 2. A Data Port = Input, B Data Port = Output

Figure 3. A Data Port = Output, B Data Port = Input



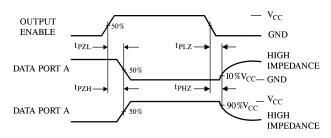
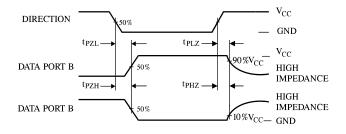


Figure 4. Switching Waveforms

Figure 5. Switching Waveforms



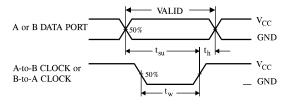


Figure 6. Switching Waveforms

Figure 7. Switching Waveforms



EXPANDED LOGIC DIAGRAM

